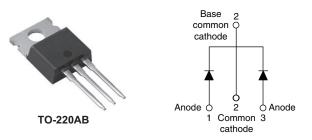
VS-MBR25...CTPbF Series, VS-MBR25...CT-N3 Series

Vishay Semiconductors



Schottky Rectifier, 2 x 15 A



PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 15 A				
V _R	35 V, 45 V				
V _F at I _F	See Electrical table				
I _{RM} max.	40 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	16 mJ				

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform (per device)	30	A			
V _{RRM}		35/45	V			
I _{FRM}	T _C = 130 °C (per leg)	30	A			
I _{FSM}	t _p = 5 μs sine	1060	A .			
V _F	30 A _{pk} , T _J = 125 °C	0.73	V			
TJ	Range	- 65 to 150	°C			

VOLTAGE RATINGS										
PARAMETER	SYMBOL	VS-MBR2535CTPbF	VS-MBR2535CT-N3	VS-MBR2545CTPbF	VS-MBR2545CT-N3	UNITS				
Maximum DC reverse voltage	V _R	35	35	45	45	M				
Maximum working peak reverse voltage	V _{RWM}		33	45	45	v				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS							
Maximum average per leg				15				
forward current per device	I _{F(AV)}	$T_{C} = 130 \ ^{\circ}C$, rated V_{R}		30				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20	Rated V _R , square wave, 20 kHz, $T_C = 130 \text{ °C}$					
Non-repetitive peak surge current	I _{ESM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	A			
	1 OM	Surge applied at rated load conditions halfwave, single phase, 60 Hz		150				
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 8 mH		16	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to Frequency limited by T_J ma		2	А			

Revision: 30-Aug-11

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RoHS

COMPLIANT

HALOGEN

FREE



VS-MBR25...CTPbF Series, VS-MBR25...CT-N3 Series

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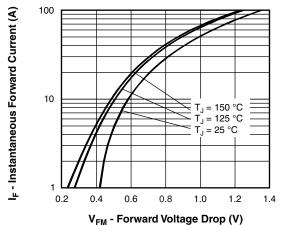
ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	30 A	T _J = 25 °C	0.82	V		
Maximum forward voltage drop	VFM (**	50 A	T _J = 125 °C	0.73	v		
Maximum instantaneous reverse current	I _{BM} ⁽¹⁾	$T_J = 25 \ ^{\circ}C$	Rated DC voltage	0.2	m۸		
Maximum Instantaneous reverse current	IRM ()	T _J = 125 °C	Haled DC Vollage	40	mA		
Threshold voltage	V _{F(TO)}			0.355	V		
Forward slope resistance	r _t	$I_{J} = I_{J} III a X III u III$	$T_J = T_J maximum$				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	700	pF			
Typical series inductance	Ls	Measured from top of termina	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

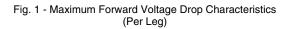
Note

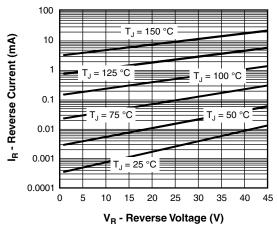
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

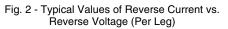
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ		- 65 to 150	°C				
Maximum storage temperature range	T _{Stg}		- 65 to 175	C				
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.5	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	0/10				
Approximate weight			2	g				
			0.07	oz.				
Mounting torque		Non-lubricated threads	6 (5)	kgf ⋅ cm				
Mounting torque maximum		Non-Iubricateu tineaus	12 (10)	(lbf ⋅ in)				
Marking device		Case style TO-220AB	MBR2	535CT				
		Case signe 10-220AD	MBR2545CT					











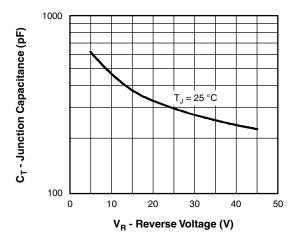


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

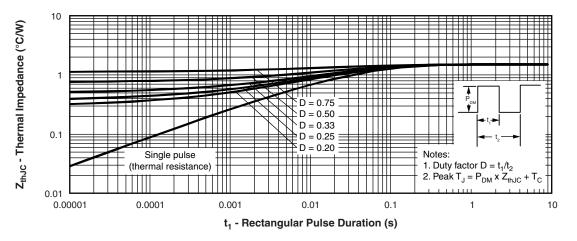
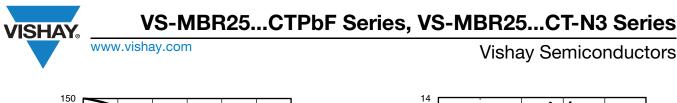


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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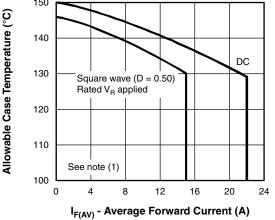


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

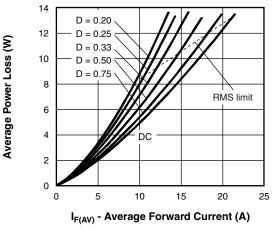


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

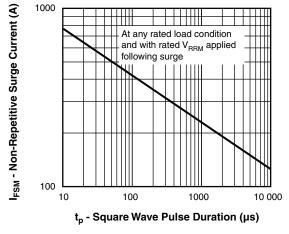


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times V_{FM} \mbox{ at } (I_{F(AV)}/D) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); } I_R \mbox{ at } V_{R1} = \mbox{Rated } V_R \end{array}$

VS-MBR25...CTPbF Series, VS-MBR25...CT-N3 Series



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ORDERING INFORMATION TABLE

Device code	VS-	MBR	25	45	СТ	PbF	
	1	2	3	4	5	6	-
	1 · 2 ·		,	niconduo 3R serie		oduct	
	3 - 4 -		rent ratii age rati	ng (30 A ngs –	.)		35 = 35 V 45 = 45 V
	5 - 6 -	. Env	rironmer	itial part ntal digit			6 compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MBR2535CTPbF	50	1000	Antistatic plastic tube				
VS-MBR2535CT-N3	50	1000	Antistatic plastic tube				
VS-MBR2545CTPbF	50	1000	Antistatic plastic tube				
VS-MBR2545CT-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
Dout moduling information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches





.ead	assignments

Diodes

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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